

# isc N-Channel MOSFET Transistor

# IPB049NE7N3

**• FEATURES**

- With TO-263( D2PAK ) packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• APPLICATIONS**

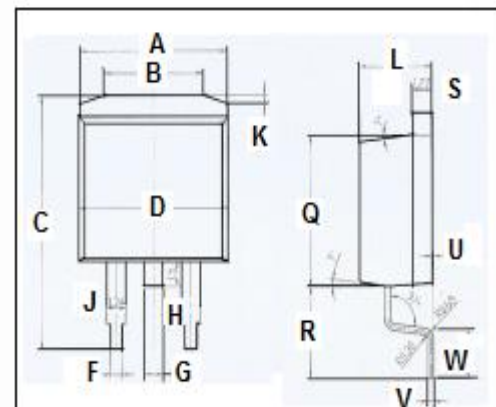
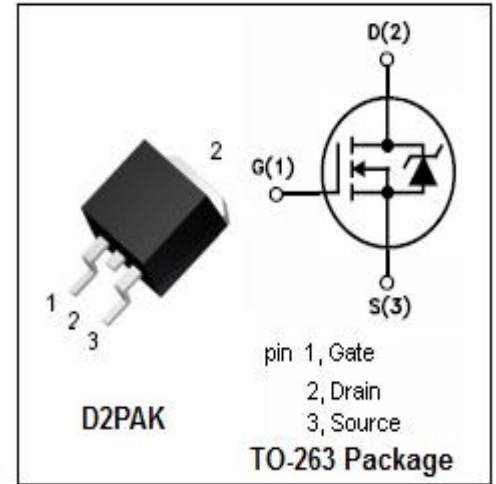
- Power supply
- Switching applications

**• ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	75	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous; T <sub>c</sub> =25°C T <sub>c</sub> =100°C	80	A
I <sub>DM</sub>	Drain Current-Single Pulsed	320	A
P <sub>D</sub>	Total Dissipation	150	W
T <sub>j</sub>	Operating Junction Temperature	175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(ch-c)</sub>	Channel-to-case thermal resistance	1	°C/W
R <sub>th(ch-a)</sub>	Channel-to-ambient thermal resistance	40	°C/W



DIM	mm	
	MIN	MAX
A	10	
B	6.6	6.8
C	15.23	15.25
D	10.15	10.17
F	0.76	0.78
G	1.26	1.28
H	1.4	1.6
J	1.33	1.35
K	0.4	0.6
L	4.6	4.8
Q	8.69	8.71
R	5.28	5.30
S	1.26	1.28
U	0.0	0.2
V	0.37	0.39
W	2.80	2.82

**isc N-Channel MOSFET Transistor****IPB049NE7N3****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=1\text{mA}$	75			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=0.091\text{mA}$	2.3		3.8	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=80A$		4.4	4.9	$\text{m}\Omega$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS}=\pm 20V; V_{DS}=0V$			$\pm 0.1$	$\mu\text{A}$
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS}=75V; V_{GS}=0V; T_C=25^{\circ}\text{C}$ $V_{DS}=75V; V_{GS}=0V; T_C=125^{\circ}\text{C}$			1 100	$\mu\text{A}$
$V_{SDF}$	Diode forward voltage	$I_{SD}=80A, V_{GS}=0V$		1.0	1.2	V

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